

## -20V/-3.2A P-Channel MOSFET

### Features

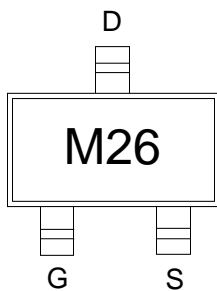
- Leading trench technology for low  $R_{DS(on)}$
- Low Gate Charge

### Application

- Video monitor
- Power management

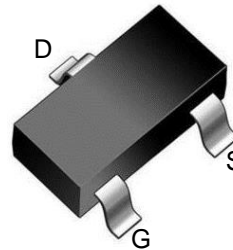
### Product Summary

$V_{DS}$	$R_{DS(ON)}$ MAX	$I_D$ MAX
-20V	65mΩ@-4.5V	-3.2A
	81mΩ@-2.5V	

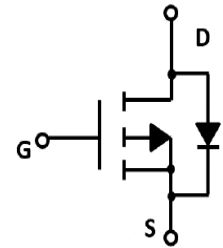


M26: Device code

Marking and pin assignment



SOT-23 top view



Schematic diagram

Absolute Maximum Ratings (TA=25°C unless otherwise noted)				
Symbol	Parameter		Rating	Unit
<b>Common Ratings (TC=25°C Unless Otherwise Noted)</b>				
$V_{DS}$	Drain-Source Breakdown Voltage		-20	V
$V_{GS}$	Gate-Source Voltage		±12	V
$T_J$	Maximum Junction Temperature		150	°C
$T_{STG}$	Storage Temperature Range		-55 to 150	°C
$I_S$	Diode Continuous Forward Current	$T_c=25^\circ\text{C}$	-3.2	A
<b>Mounted on Large Heat Sink</b>				
$I_{DM}$	Pulse Drain Current Tested	$T_c=25^\circ\text{C}$	-12	A
$I_D$	Continuous Drain Current@GS=10V	$T_c=25^\circ\text{C}$	-3.2	A
$P_D$	Maximum Power Dissipation	$T_c=25^\circ\text{C}$	0.35	W
$R_{\theta JA}$	Thermal Resistance Junction-to-Ambient		357	°C/W

<b>Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)</b>						
<b>Symbol</b>	<b>Parameter</b>	<b>Condition</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
B <sub>V(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA	-20	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V	--	--	-1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-0.4	-0.75	-1.0	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-3.2A	--	56	65	mΩ
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-2.8A	--	70	81	mΩ
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-2.3A	--	--	110	mΩ
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V, f=1MHz	--	400	--	pF
C <sub>OSS</sub>	Output Capacitance		--	73	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	54	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =-10V, I <sub>D</sub> =-3A, V <sub>GS</sub> =-4.5V	--	5.3	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	0.7	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	1.2	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =-10V, I <sub>D</sub> =-1A, V <sub>GS</sub> =-4.5V, R <sub>G</sub> =2.8Ω	--	11	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	35	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	28	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	10	--	nS
<b>Source- Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>S</sub> =-2.8A,	--	--	-1.2	V

## Typical Operating Characteristics

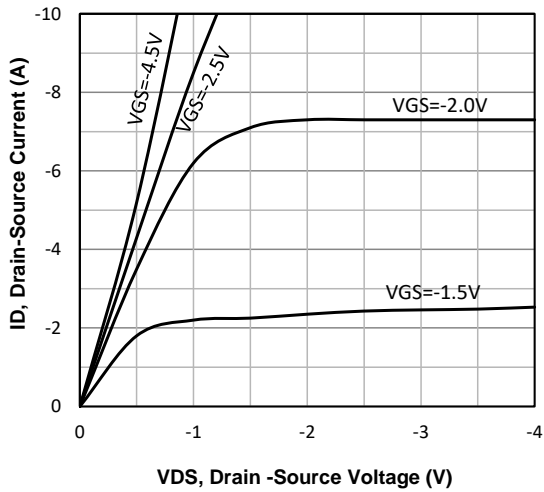


Fig1. Typical Output Characteristics

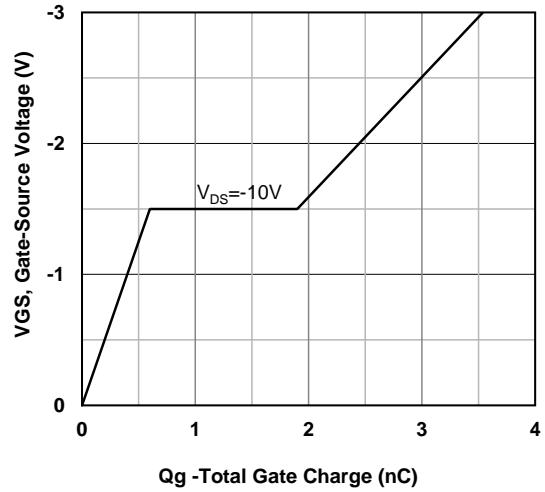


Fig2. Typical Gate Charge Vs. Gate-Source Voltage

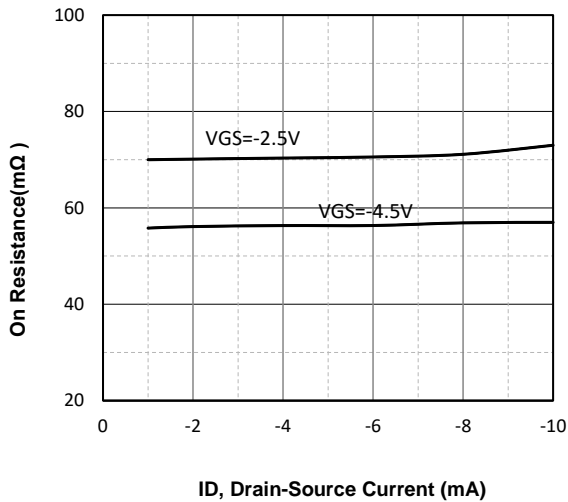


Fig3. Drain-Source on Resistance

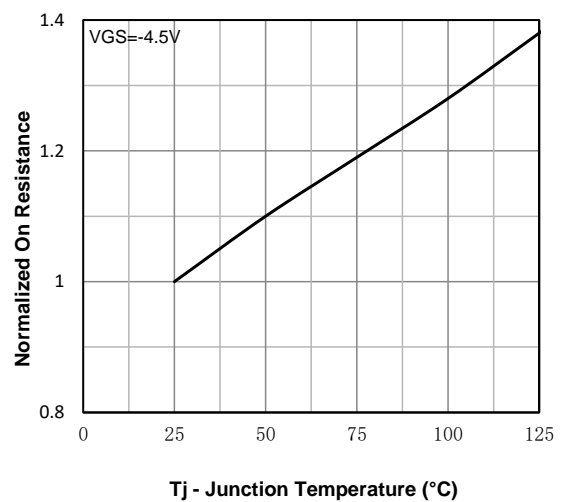


Fig4. Normalized On-Resistance Vs. Temperature

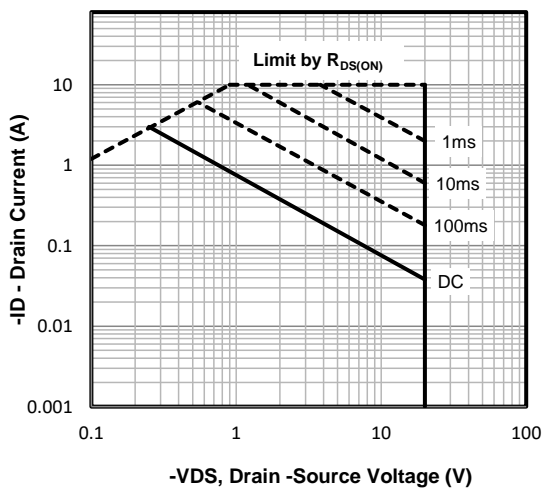


Fig5. Maximum Safe Operating Area

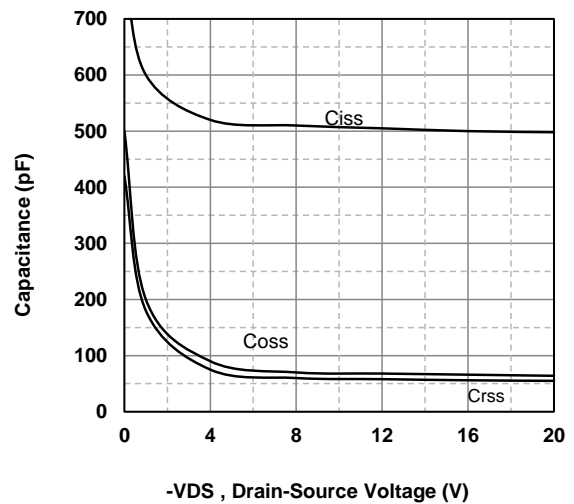
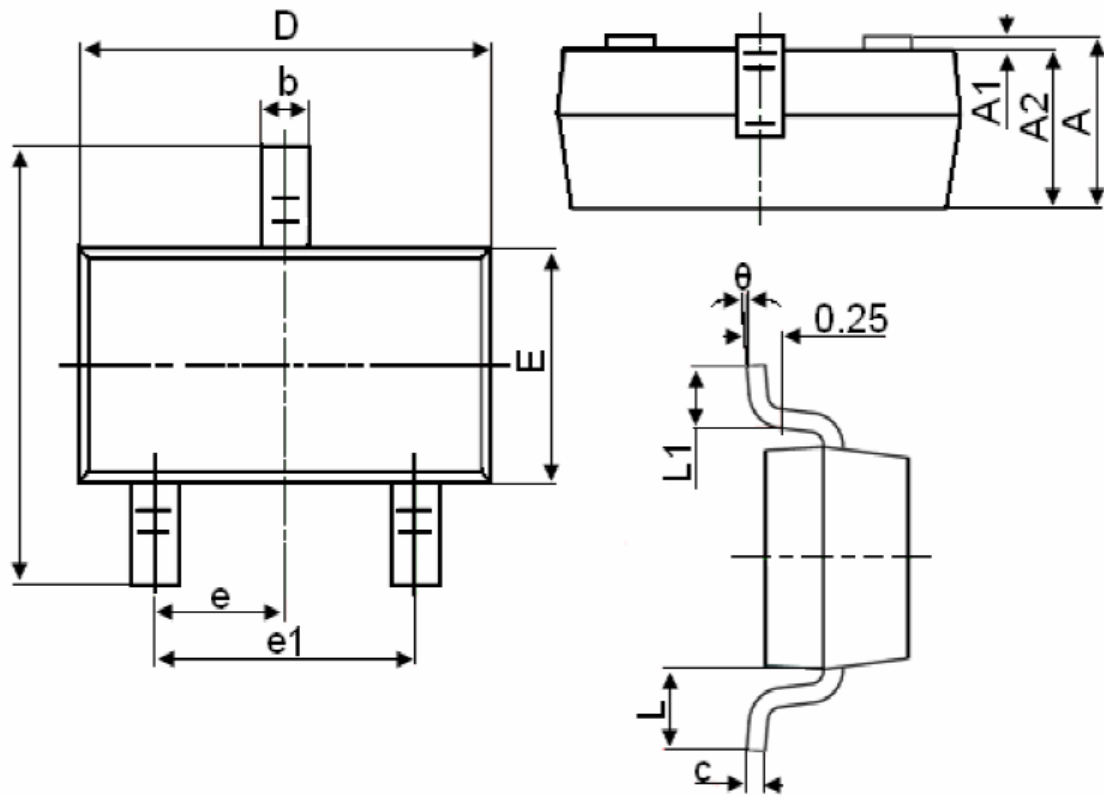


Fig6 Typical Capacitance Vs. Drain-Source Voltage

**SOT-23 Package information**


Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550REF		0.022REF	
L1	0.300	0.500	0.012	0.020
$\theta$	$0^\circ$	$8^\circ$	$0^\circ$	$8^\circ$

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